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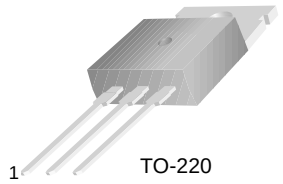
FAIRCHILD SEMICONDUCTOR™

Jameco Part Number 33048

TIP31 Series(TIP31/31A/31B/31C)

Medium Power Linear Switching Applications

- Complementary to TIP32/32A/32B/32C



TO-220

1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : TIP31	40	V
	: TIP31A	60	V
	: TIP31B	80	V
	: TIP31C	100	V
V_{CEO}	Collector-Emitter Voltage : TIP31	40	V
	: TIP31A	60	V
	: TIP31B	80	V
	: TIP31C	100	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	3	A
I_{CP}	Collector Current (Pulse)	5	A
I_B	Base Current	1	A
P_C	Collector Dissipation (T_C=25°C)	40	W
P_C	Collector Dissipation (T_a=25°C)	2	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V_{CEO}(sus)	* Collector-Emitter Sustaining Voltage				
	: TIP31	I_C = 30mA, I_B = 0	40		V
	: TIP31A		60		V
	: TIP31B		80		V
	: TIP31C		100		V
I_{CEO}	Collector Cut-off Current				
	: TIP31/31A	V_{CE} = 30V, I_B = 0		0.3	mA
	: TIP31B/31C	V_{CE} = 60V, I_B = 0		0.3	mA
I_{CES}	Collector Cut-off Current				
	: TIP31	V_{CE} = 40V, V_{EB} = 0		200	μA
	: TIP31A	V_{CE} = 60V, V_{EB} = 0		200	μA
	: TIP31B	V_{CE} = 80V, V_{EB} = 0		200	μA
	: TIP31C	V_{CE} = 100V, V_{EB} = 0		200	μA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 5V, I_C = 0		1	mA
h_{FE}	* DC Current Gain	V_{CE} = 4V, I_C = 1A	25		
		V_{CE} = 4V, I_C = 3A	10	50	
V_{CE}(sat)	* Collector-Emitter Saturation Voltage	I_C = 3A, I_B = 375mA		1.2	V
V_{BE}(sat)	* Base-Emitter Saturation Voltage	V_{CE} = 4V, I_C = 3A		1.8	V
f_T	Current Gain Bandwidth Product	V_{CE} = 10V, I_C = 500mA	3.0		MHz

* Pulse Test: PW≤300μs, Duty Cycle≤2%

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Typical Characteristics

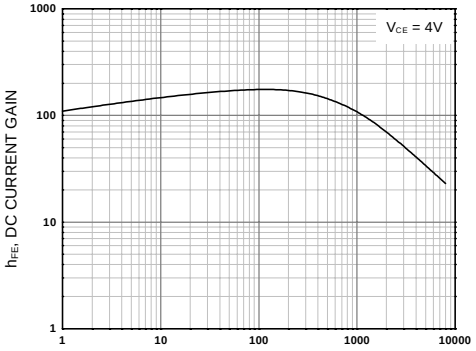

Figure 1. DC current Gain

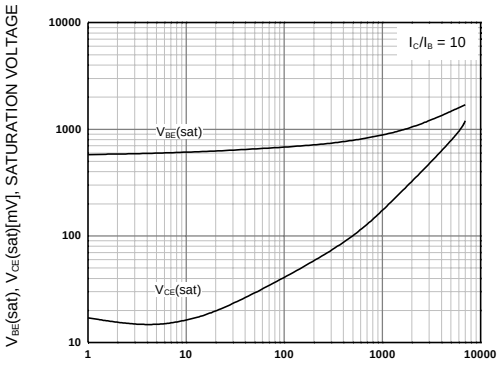

Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

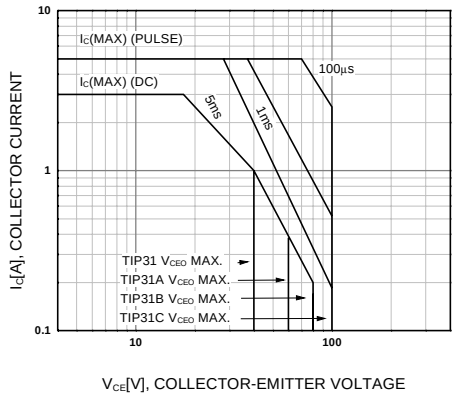

Figure 3. Safe Operating Area

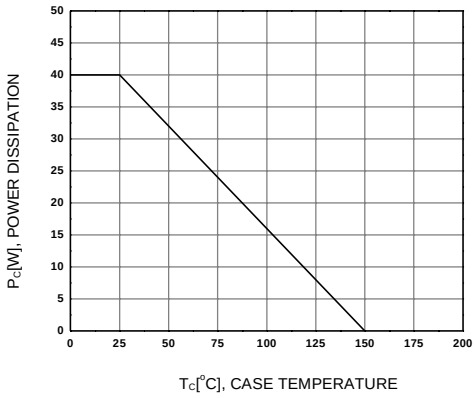

Figure 4. Power Derating

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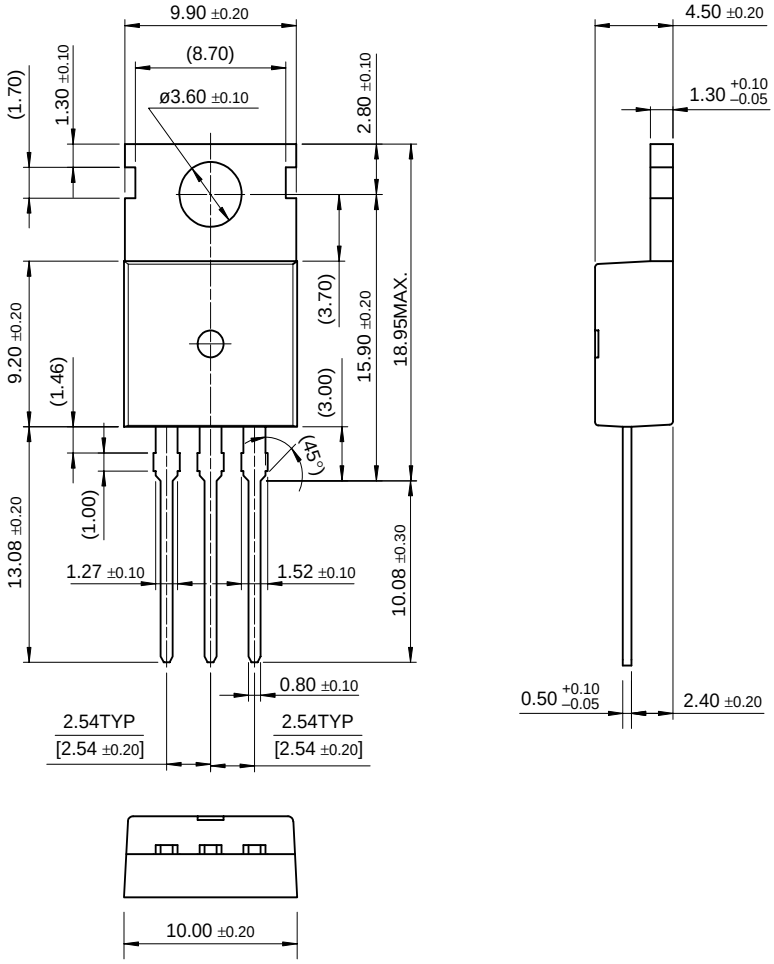
Package Demensions

TO-220



Dimensions in Millimeters

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